Technical Data
Data Sheet N1204, Rev. -

Green Products

242NQ030-1 SCHOTTKY RECTIFIER

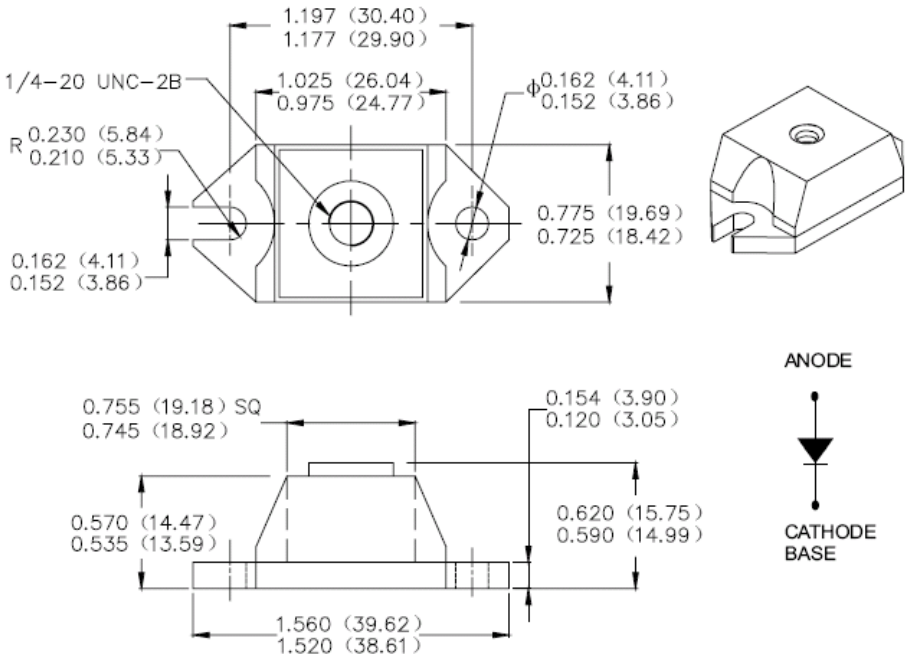
Applications:

● Switching power supply ● Converters ● Free-Wheeling diodes ● Reverse battery protection

Features:

- **150℃T_J operation**
- **Unique high power, Half-Pak module**
- **Replaces three parallel DO-5'S**
- **Easier to mount and lower profile than DO-5'S**
- **High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance**
- **Very low forward voltage drop**
- **High frequency operation**
- **Guard ring for enhanced ruggedness and long term reliability**
- **This is a Pb − Free Device**
- **All SMC parts are traceable to the wafer lot**
- **Additional testing can be offered upon request**

Mechanical Dimensions: In mm/Inches



PRM1-1(HALF PAK Module)

MARKING,MOLDING RESIN
Marking for 242NQ030-1, 1st row SS YYWWL, 2nd row 242NQ030-1
Where YY is the manufacture year
WW is the manufacture week code
L is the wafer's Lot Number
Molding resin
Epoxy resin UL:94V-0

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	30	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @T_C =111°C, rectangular wave form	240	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	3600	A
Non-Repetitive Avalanche Energy	E_{AS}	T_J=25℃,I_{AS}=48A,L=0.19mH	216	mJ
Repetitive Avalanche Current	I_{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. V_A=1.5×V_R typical	48	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 240A, Pulse, T_J = 25 °C @ 480A, Pulse, T_J = 25 °C	0.51 0.62	V
	V_{F2}	@ 240A, Pulse, T_J = 125 °C @ 480A, Pulse, T_J = 125 °C	0.42 0.54	V
Max. Reverse Current (per leg) *	I_{R1}	@V_R = rated V_R T_J = 25 °C	20	mA
	I_{R2}	@V_R = rated V_R T_J = 125 °C	1120	mA
Max. Junction Capacitance (per leg)	C_T	@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz	14800	pF
Typical Series Inductance (per leg)	L_S	Measured lead to lead 5 mm from package body	5.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

* Pulse Width < 300μs, Duty Cycle <2%

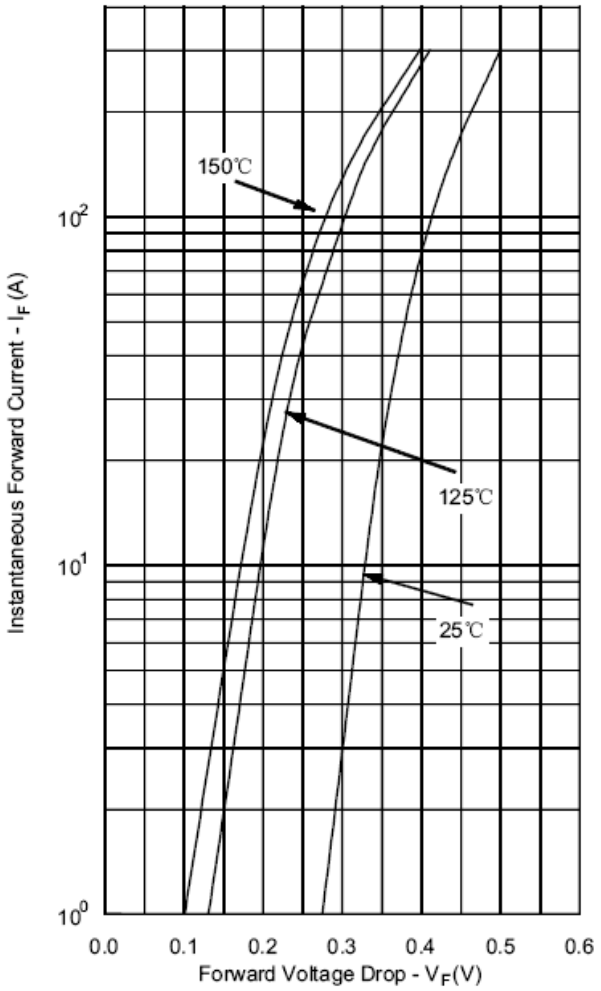
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units
Max. Junction Temperature	T_J	-	-55 to +150		°C
Max. Storage Temperature	T_{stg}	-	-55 to +150		°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.20		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.15		°C/W
Mounting Torque	T_M	-	Mounting Torque	23(min) 29(max)	Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	25.6		g
Case Style	PRM1-1				

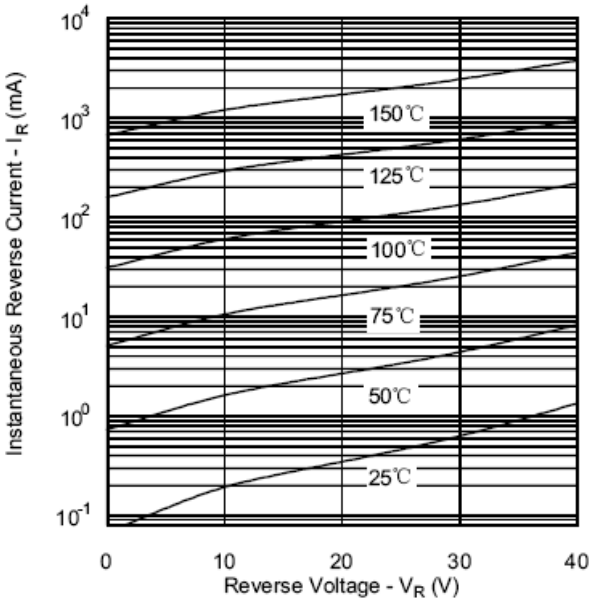
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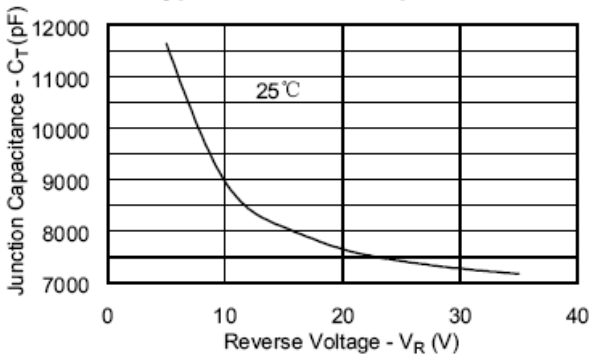
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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